



1N5817 THRU 1N5819

SCHOTTKY BARRIER RECTIFIER

TECHNICAL
SPECIFICATION

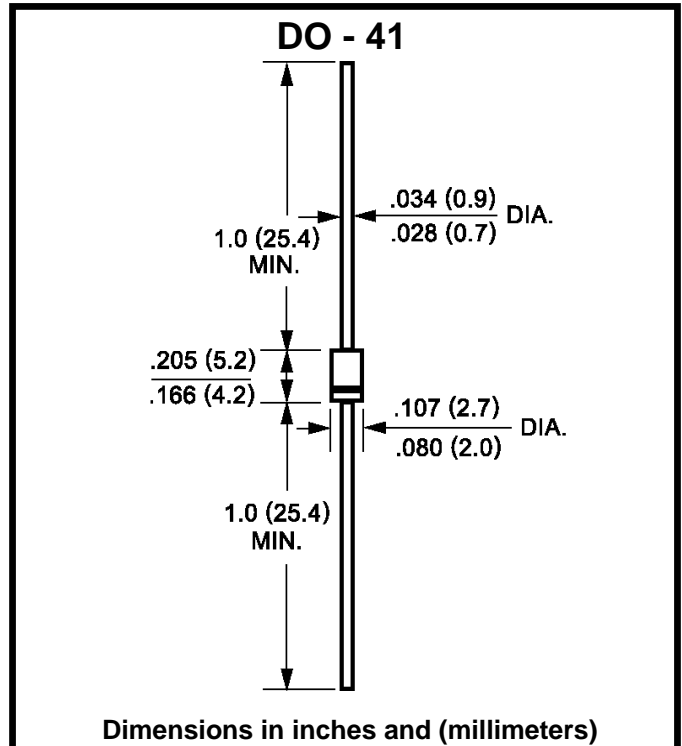
VOLTAGE: 20 TO 40V CURRENT: 1.0A

FEATURES

- Epitaxial construction for chip
- High current capability
- Low forward voltage drop
- Low power loss, high efficiency
- High surge capability
- High temperature soldering guaranteed:
250°C/10sec/0.375"(9.5mm) lead length
at 5 lbs tension

MECHANICAL DATA

- Terminal: Plated axial leads solderable per
MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O
recognized flame retardant epoxy
- Polarity: Color band denotes cathode
- Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	1N5817	1N5818	1N5819	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	V
Maximum RMS Voltage	V_{RMS}	14	21	28	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	V
Maximum Average Forward Rectified Current (9.5mm lead length, at $T_L=90^\circ\text{C}$)	$I_{F(AV)}$	1.0			A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I_{FSM}	25			A
Maximum Forward Voltage (at 1.0A DC)	V_F	0.45	0.55	0.6	V
Maximum DC Reverse Current (at rated DC blocking voltage)	I_R	1.0 10.0			mA mA
Typical Junction Capacitance (Note 1)	C_J	110			pF
Typical Thermal Resistance (Note 2)	$R_{\theta(ja)}$	50			°C/W
Storage and Operation Junction Temperature	T_{STG}, T_J	-65 to +125			°C

Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0V_{dc}

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, vertical P.C. board mounted